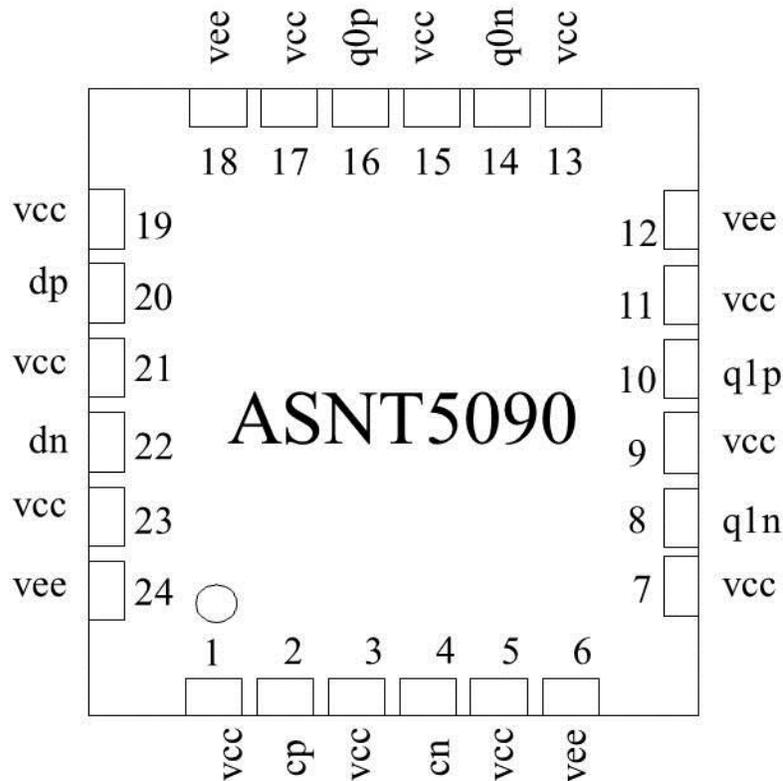




ASNT5090-PQC DC-32Gbps Broadband Digital 1:2 Demultiplexer

- High speed broadband 1:2 Demultiplexer
- Exhibits low jitter and limited temperature variation over industrial temperature range
- Ideal for high speed proof-of-concept prototyping
- Fully differential CML input interfaces
- Fully differential CML output interface with 400mV single-ended swing
- Single +3.3V or -3.3V power supply
- Power consumption: 730mW
- Fabricated in SiGe for high performance, yield, and reliability
- Standard MLF/QFN 24-pin package



DESCRIPTION

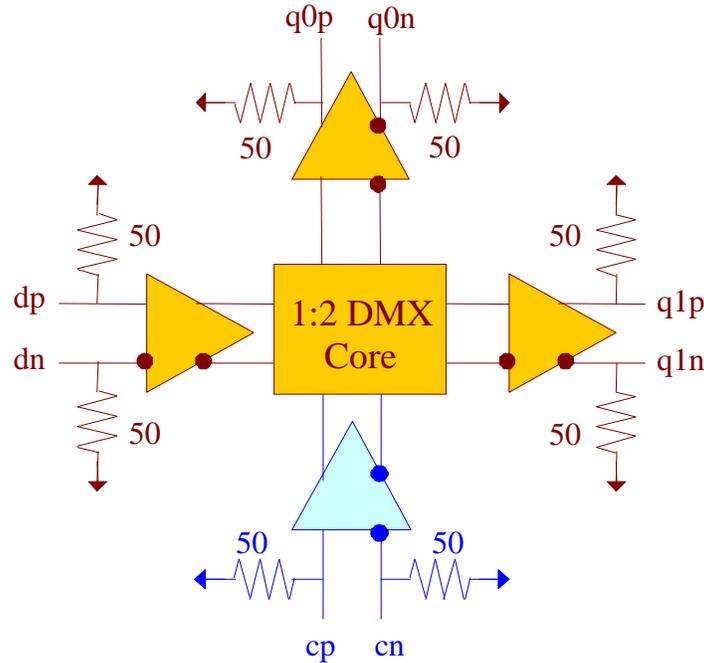


Fig. 1. Functional Block Diagram

The temperature stable ASNT5090-PQC SiGe IC can be utilized as a high speed 1:2 demultiplexer, and is intended for use in high-speed measurement / test equipment. The IC shown in Fig. 1 can receive a high speed differential data input signal dp/dn and effectively demultiplex it into two high speed differential data output signals $q0p/q0n$ and $q1p/q1n$ by using a high speed differential clock input signal cp/cn .

The part's I/O's support the CML logic interface with on chip 50Ω termination to VCC and may be used differentially, AC/DC coupled, single-ended, or in any combination (see also POWER SUPPLY CONFIGURATION). In the DC-coupling mode, the input signal's common mode voltage should comply with the specifications shown in ELECTRICAL CHARACTERISTICS. In the AC-coupling mode, the input termination provides the required common mode voltage automatically. The differential DC signaling mode is recommended for optimal performance.

POWER SUPPLY CONFIGURATION

The part can operate with either negative supply ($VCC = 0.0V = \text{ground}$ and $VEE = -3.3V$), or positive supply ($VCC = +3.3V$ and $VEE = 0.0V = \text{ground}$). In case of the positive supply, all I/Os need AC termination when connected to any devices with 50Ω termination to ground. Different PCB layouts will be needed for each different power supply combination.



All the characteristics detailed below assume $V_{CC} = 0.0V$ and $V_{EE} = -3.3V$.

ABSOLUTE MAXIMUM RATINGS

Caution: Exceeding the absolute maximum ratings may cause damage to this product and/or lead to reduced reliability. Functional performance is specified over the recommended operating conditions for power supply and temperature only. AC and DC device characteristics at or beyond the absolute maximum ratings are not assumed or implied. All min and max voltage limits are referenced to ground.

Table 1. Absolute Maximum Ratings

Parameter	Min	Max	Units
Supply Voltage (V_{EE})		-3.6	V
Power Consumption		0.80	W
RF Input Voltage Swing (SE)		1.0	V
Case Temperature		+90	$^{\circ}C$
Storage Temperature	-40	+100	$^{\circ}C$
Operational Humidity	10	98	%
Storage Humidity	10	98	%

TERMINAL FUNCTIONS

TERMINAL			DESCRIPTION
Name	No.	Type	
High-Speed I/Os			
dp	20	CML input	Differential data input signals with internal 50Ω termination to V_{CC} .
dn	22		
q0p	16	CML output	Differential data output signals with internal 50Ω termination to V_{CC} .
q0n	14		
q1p	10	CML output	Differential data output signals with internal 50Ω termination to V_{CC} .
q1n	8		
cp	2	CML input	Differential clock input signals with internal 50Ω termination to V_{CC} .
cn	4		
Supply and Termination Voltages			
Name	Description		Pin Number
vcc	Positive power supply. (+3.3V or 0)		1, 3, 5, 7, 9, 11, 13, 15, 17, 19, 21, 23
vee	Negative power supply. (0V or -3.3V)		6, 12, 18, 24



ELECTRICAL CHARACTERISTICS

PARAMETER	MIN	TYP	MAX	UNIT	COMMENTS
General Parameters					
v _{ee}	-3.1	-3.3	-3.5	V	±6%
v _{cc}		0.0		V	External ground
I _{vee}		220		mA	
Power consumption		730		mW	
Junction temperature	-40	25	125	°C	
HS Input Data (dp/dn)					
Data rate	DC		32	Gbps	
Swing	0.05		1.0	V	Differential or SE, p-p
CM Voltage Level	v _{cc} -0.8		v _{cc}	V	Must match for both inputs
HS Input Clock (cp/cn)					
Frequency	DC		16	GHz	
Swing	0.05		1.0	V	Differential or SE, p-p
CM Voltage Level	v _{cc} -0.8		v _{cc}	V	Must match for both inputs
Duty cycle	45	50	55	%	
HS Output Data (q0p/q0n, q1p/q1n)					
Data rate	DC		16	Gbps	
Logic "1" level		v _{cc}		V	
Logic "0" level		v _{cc} -0.4		V	With external 50Ω DC termination
Rise/Fall times	7	9	11	ps	20%-80%
Output Jitter			1	ps	Peak-to-peak

PACKAGE INFORMATION

The chip die is housed in a standard 24-pin QFN package shown in Fig. 2. It is recommended that the center heat slug located on the back side of the package is soldered to the v_{ee} plain that is ground for the positive supply or power for the negative supply.

The part's identification label is ASNT5090-PQC. The first 8 characters of the name before the dash identify the bare die including general circuit family, fabrication technology, specific circuit type, and part version while the 3 characters after the dash represent the package's manufacturer, type, and pin out count.

This device complies with the Restriction of Hazardous Substances (RoHS) per 2011/65/EU for all ten substances.

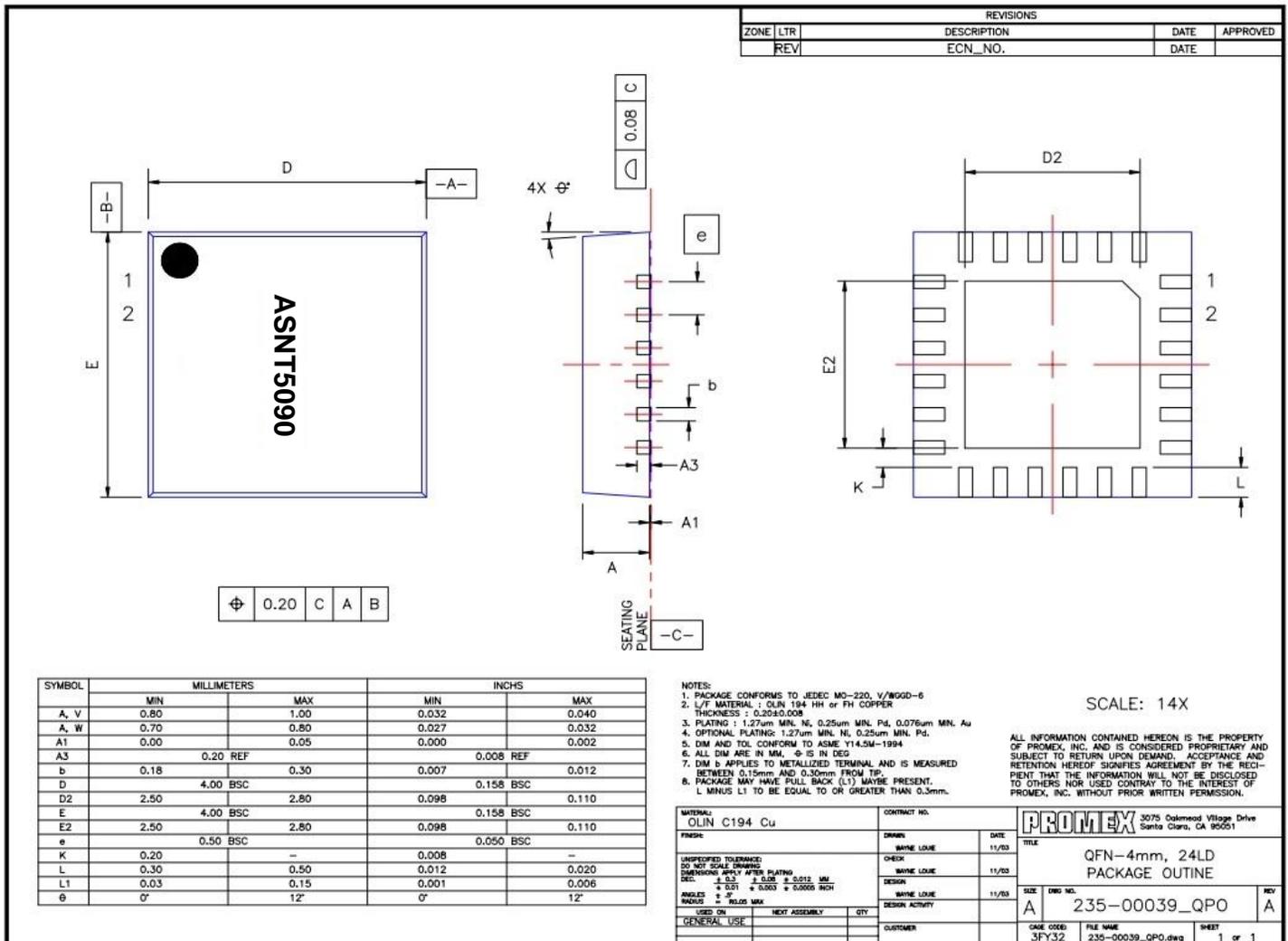


Fig. 2. QFN 24-Pin Package Drawing (All Dimensions in mm)



REVISION HISTORY

Revision	Date	Changes
2.1.2	05-2020	Updated Package Information
2.0.2	07-2019	Updated Letterhead
2.0.1	02-2013	Revised title Revised pin out drawing Revised functional block diagram Added power supply configuration Added absolute maximum ratings Revised terminal functions Revised electrical characteristics Revised package information Added mechanical drawing Format correction
1.2	04-2010	Revised electrical characteristics Added package information
1.0	10-2008	First release